



SGM4810

Dual 158mW Headphone Amplifier with Active High Shutdown Mode

GENERAL DESCRIPTION

The SGM4810 is a dual audio power amplifier capable of delivering 158mW per channel of continuous average power with less than 0.1% distortion (THD + N) when it drives a 16Ω speaker from a 5.0V power supply. It is designed to maximize audio performance in portable applications such as mobile phone. The portable application requires audio power amplifier has minimum of external components and can operate from a single 2.5V to 5.5V power supply.

SGM4810 features an externally controlled, active-high, micropower consumption shutdown mode, as well as an internal thermal shutdown protection mechanism.

The SGM4810 does not require bootstrap capacitors or snubber networks. It is optimally suited for low-power portable systems.

For maximum flexibility, the SGM4810 provides an externally controlled gain (with resistors), as well as an externally controlled turn-on time (with the bypass capacitor).

The SGM4810 is available in Pb-free MSOP-8 package. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES

- **Active-High Shutdown Mode**
- **158mW into 16Ω Load from 5V Power Supply at THD+N = 0.1% Typical (per Channel)**
- **87mW into 32Ω Load from 5V Power Supply at THD+N = 0.1% Typical (per Channel)**
- **Unity Gain Stable**
- **2.5V to 5.5V Operation**
- **Shutdown Pin is Compatible with 1.8V Logic**
- **Shutdown Current: 0.5μA (TYP)**
- **Click and Pop Reduction Circuitry**
- **-40°C to +85°C Operating Temperature Range**
- **Pb-Free MSOP-8 Package**

APPLICATIONS

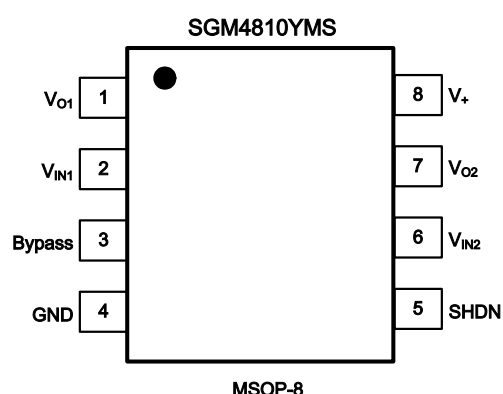
Portable Systems
Headphone Amplifier
Microphone Preamplifier
Notebook Computers
Mobile Phone
PDAs
GPS



PACKAGE/ORDERING INFORMATION

MODEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
SGM4810	SGM4810YMS/TR	MSOP-8	Tape and Reel, 3000	SGM4810YMS

PIN CONFIGURATION (Top View)



CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage.....	6V
Input Voltage.....	-0.3V to $(V_+) + 0.3V$
Storage Temperature Range.....	-65°C to +150°C
Junction Temperature.....	150°C
Operating Temperature Range.....	-40°C to +85°C
Lead Temperature Range (Soldering 10 sec)260°C
ESD Susceptibility	
HBM.....	4KV
MM.....	400V

NOTES

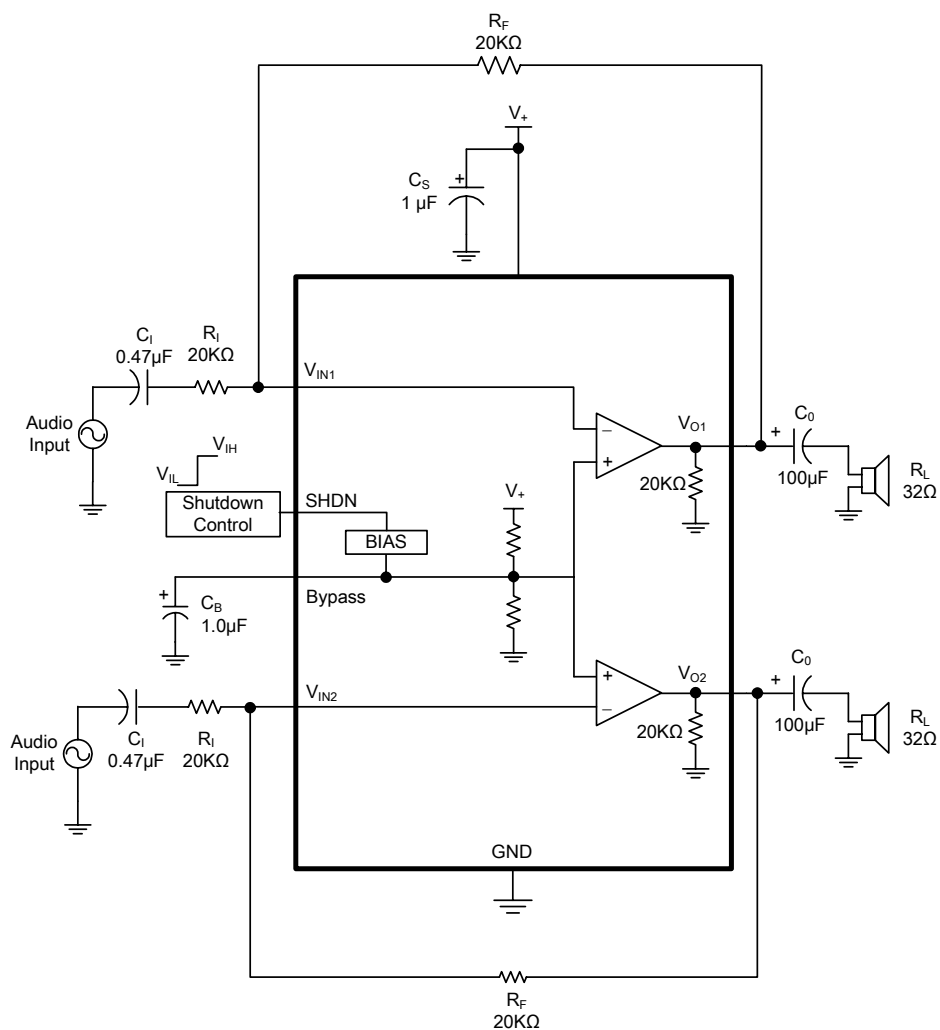
Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS: $T_A = 25^\circ\text{C}$

PARAMETER	SYMBOL	CONDITIONS		SGM4810			UNITS	
				MIN	TYP	MAX		
Supply Voltage	V ₊			2.5		5.5	V	
Shutdown Current	I _{SD}	V _{IN} = 0V, V _{SHDN} = V ₊ = 5.0V			0.5	4	μA	
		V _{IN} = 0V, V _{SHDN} = V ₊ = 3.3V			0.5			
		V _{IN} = 0V, V _{SHDN} = V ₊ = 2.6V			0.1			
Output Offset Voltage	V _{OS}	V _{IN} = 0V, V _{SHDN} = GND		-50	1	50	mV	
Quiescent Power Supply Current	I _Q	V _{IN} = 0V, V _{SHDN} = GND	V ₊ = 5.0V, No Load		1.75	2.8	mA	
			V ₊ = 3.3V, No Load		1.64			
			V ₊ = 2.6V, No Load		1.58			
Shutdown Voltage Input High	V _{SDIH}			1.8			V	
Shutdown Voltage Input Low	V _{SDIL}					0.4	V	
Output Power (per Channel)	P _O	f = 1kHz THD+N=0.1%	V ₊ = 5.0V	R _L = 16Ω		158		mW
				R _L = 32Ω		87		
			V ₊ = 3.6V	R _L = 16Ω		84		
				R _L = 32Ω		47		
			V ₊ = 3.0V	R _L = 16Ω		58		
				R _L = 32Ω		33		
			V ₊ = 2.6V	R _L = 16Ω		42		
				R _L = 32Ω		25		
Total Harmonic Distortion + Noise	THD+N	P _O = 78mWrms, V ₊ = 5.0V, R _L = 32Ω, f = 20Hz to 20kHz			0.3		%	
Channel Separation	Crosstalk	R _L = 32Ω, P _O = 70mW, V ₊ = 5.0V, f = 1kHz			-100		dB	
Power Supply Rejection Ratio	PSRR	f = 217Hz	V ₊ = 5.0V		-62		dB	
			V ₊ = 3.6V		-62			
			V ₊ = 3.0V		-62			
			V ₊ = 2.6V		-62			
		f = 1kHz	V ₊ = 5.0V		-71			
			V ₊ = 3.6V		-71			
			V ₊ = 3.0V		-71			
			V ₊ = 2.6V		-71			

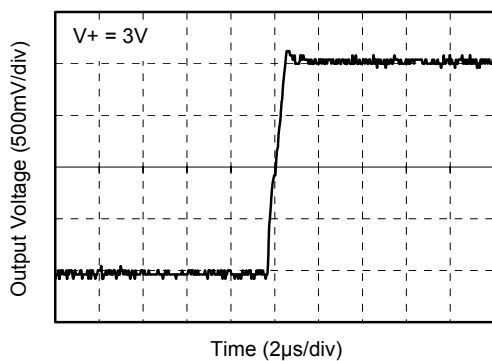
Specifications subject to changes without notice.

TYPICAL APPLICATION

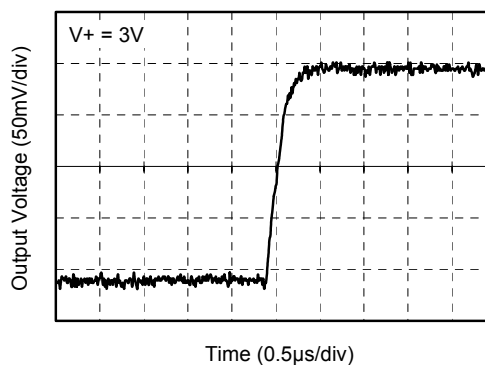


TYPICAL PERFORMANCE CHARACTERISTICS

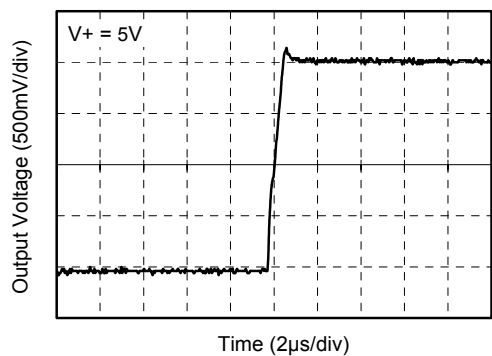
Large Signal Step Response



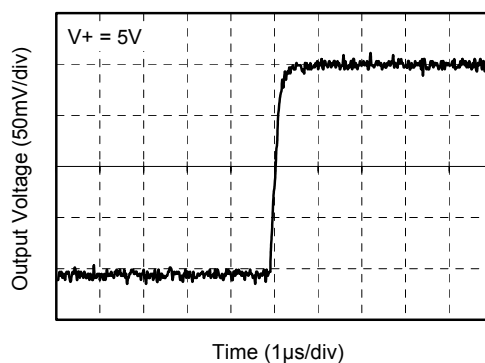
Small Signal Step Response



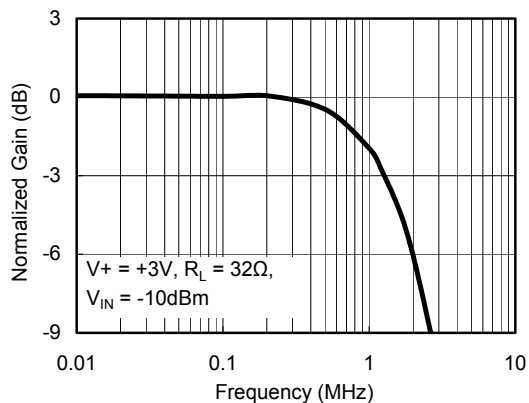
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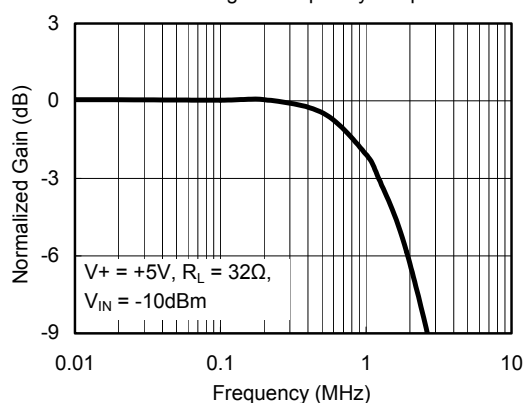
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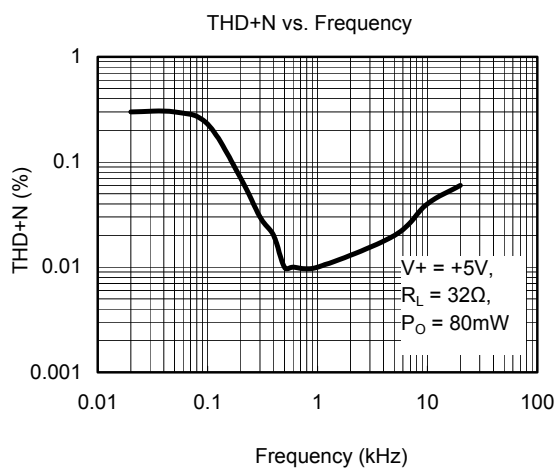
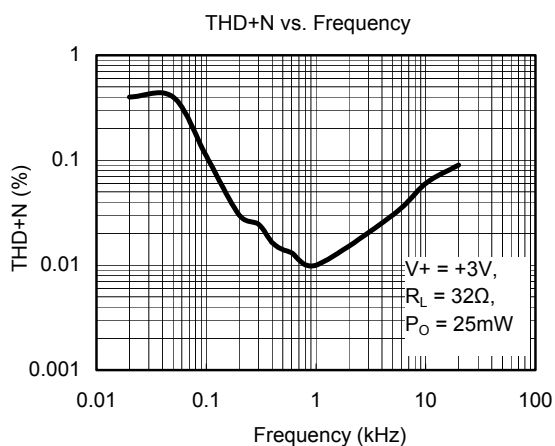
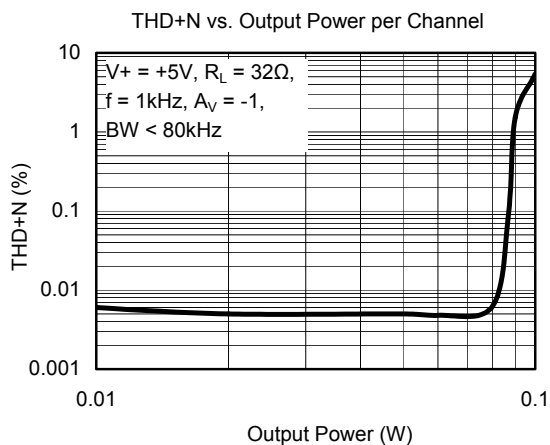
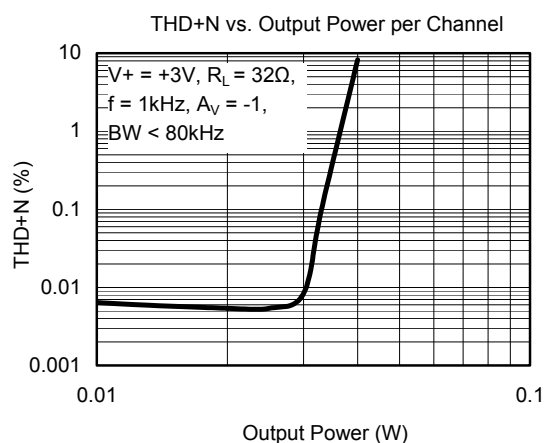
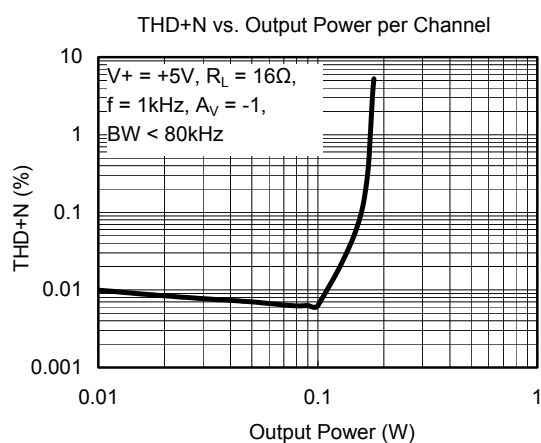
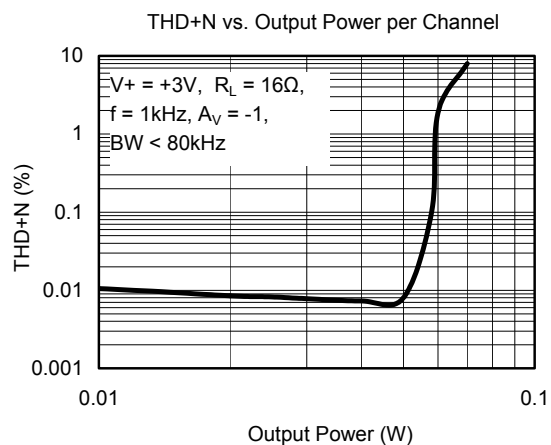
Small Signal Frequency Response



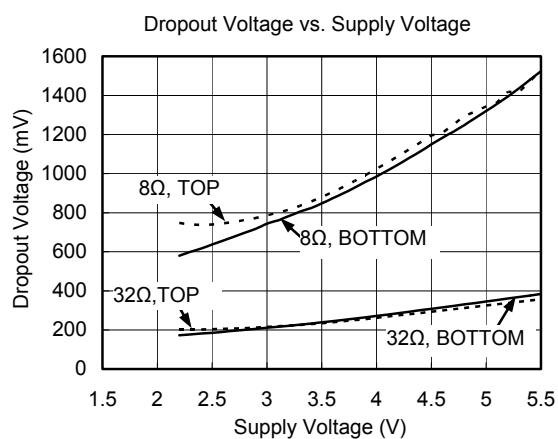
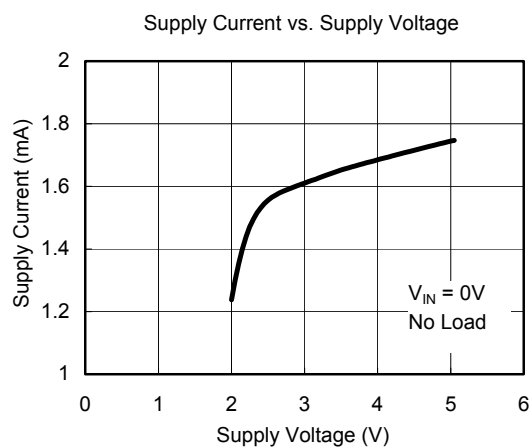
Small Signal Frequency Response



TYPICAL PERFORMANCE CHARACTERISTICS

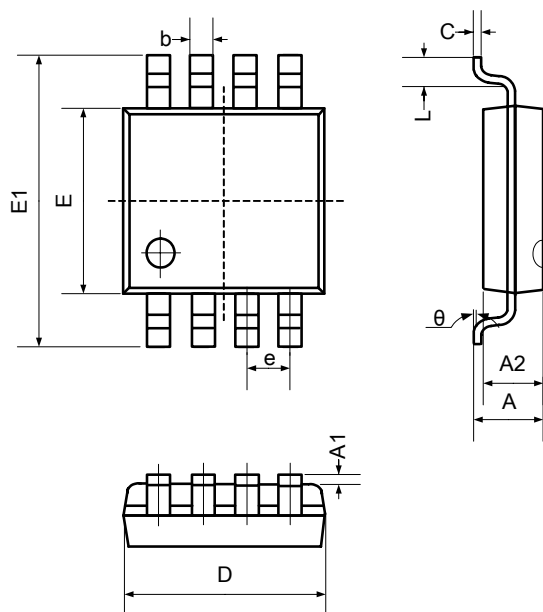


TYPICAL PERFORMANCE CHARACTERISTICS



PACKAGE OUTLINE DIMENSIONS

MSOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.800	1.200	0.031	0.047
A1	0.000	0.200	0.000	0.008
A2	0.760	0.970	0.030	0.038
b	0.30 TYP		0.012 TYP	
C	0.15 TYP		0.006 TYP	
D	2.900	3.100	0.114	0.122
e	0.65 TYP		0.026 TYP	
E	2.900	3.100	0.114	0.122
E1	4.700	5.100	0.185	0.201
L	0.410	0.650	0.016	0.026
θ	0°	6°	0°	6°

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SGMICRO is dedicated to provide high quality and high performance analog IC products to customers. All SGMICRO products meet the highest industry standards with strict and comprehensive test and quality control systems to achieve world-class consistency and reliability.

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